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An application of a quantum wave impedance method to finite periodic structures

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Abstract

The relations between a quantum wave impedance function and elements of transfer and scattering matrixes for quantum mechanical systems with arbitrary localized form of potential were established. Obtained results allows using the advantages of both methods, namely a transfer matrix technique and a quantum wave impedance approach, for an investigating of nanosystems with a complicated geometry of a potential. A finit Dirac comb was solved and expressions for Tamm's levels in this system were derived within both approaches.

1 Introduction

Heterostructures with an arbitrary form of a potential energy inside can be handled through the discretization of potential changes and following using a variety of different methods. Among the most popular are a transfer matrix approach [1, 2, 3, 4, 5, 6, 7, 8, 9, 10], a finite difference method [11, 12], a quantum wave impedance approach [13, 14, 15, 16, 17].

Both the transfer matrix technique and a quantum wave impedance method [18, 19] are widely used for solving quantum systems with a complicated geometry of a potential. These formalisms can be used for studying a propagation of both quantum particles and electromagnetic, acoustic or elastic waves. They allow calculating a transmission and a reflection amplitudes as well as finding energies of bound states.

Within a transfer matrix approach a wave function and its first derivative (in an arbitrary region with a constant value of potential energy) are related by a transfer 2×2 matrix with

the ones of the next region. The main advantage of this method is that it enables a simple representation of a solution of a Shrödinger equation through cascading 2×2 matrices. But this approach also has its drawbacks [20, 21, 22]. Using a quantum wave impedance method instead of two boundary conditions for a wave function and its first derivative it is only one boundary condition for a quantum wave impedance function. It allows signifacant simplifying the process of iterative calculation of a quantum wave impedance, which we have illustarted in our previous papers [23, 24, 25].

Thus the question arise: how to combine advantages of both approaches especially in the area of investigating of finit periodic systems since a quantum wave impedance approach has much simple procedure of its iterative determination while within a transfer matrix formalizm the approach for a calculation of sequence of finit number of identical potential regions is well developed [2, 4]. Finding an answer for this question is the issue of this paper.

2 Relation between a transfer matrix and a quantum wave impedance

Consider a localized potential of a following form

$$U(x) = \begin{cases} U_1, & x \leq a \\ f(x), & a < x < b \\ U_2, & x \geq b \end{cases} . \tag{1}$$

The motion of a quantum particle in the presence of the potential in 1D is governed by a Schrödinger equation. Its solution in the region $x \leq a$ is

$$\psi_{x \leq a}(x) = A_+ \exp[ik_1 x] + A_- \exp[-ik_1 x] \tag{2}$$

and in the region $x \geq b$:

$$\psi_{x \geq b}(x) = B_+ \exp[ik_2 x] + B_- \exp[-ik_2 x], \tag{3}$$

where $k_1 = \sqrt{2m(E - U_1)}/\hbar$, $k_2 = \sqrt{2m(E - U_2)}/\hbar$.

Usually, one relates the amplitudes A_+, A_- of the waves to the left side of the potential to those B_+, B_- on the right side. This defines the transfer matrix T.

$$\begin{pmatrix} A_+ \exp[ik_1 a] \\ A_- \exp[-ik_1 a] \end{pmatrix} = T_{ab} \begin{pmatrix} B_+ \exp[ik_2 b] \\ B_- \exp[-ik_2 b] \end{pmatrix}. \tag{4}$$

It is well-known [4] that components of a transfer matrix can be expressed through a transmission t and a reflection r amplitudes :

$$T_{ab} = \begin{pmatrix} \frac{1}{t_{ab}} & \frac{r^*_{ab}}{t^*_{ab}} \\ \frac{r_{ab}}{t_{ab}} & \frac{1}{t^*_{ab}} \end{pmatrix} \tag{5}$$

and

$$T_{ba} = \begin{pmatrix} \frac{1}{t_{ab}} & -\frac{r_{ab}}{t_{ab}} \\ -\frac{r^*_{ab}}{t^*_{ab}} & \frac{1}{t^*_{ab}} \end{pmatrix}, \tag{6}$$

where t_{ab} is the transmission amplitude, r_{ab} is the reflection amplitude. Both these result and the condition $\det|T_{ab}| = 1$ are the consequence of a time-reversal invariance and a conservation of a current density.

We see that $t_{ab} = t_{ba}$ and $\frac{r_{ba}}{t_{ba}} = -\frac{r^*_{ab}}{t^*_{ab}}$ because the scattering is symmetric with respect to the time inversion and $|t|^2 + |r|^2 = 1$ which is the result of a conservation of a flux.

The transfer matrix approach gives us the possibility to study the properties of the sample through scattering experiments. Assume that far from the sample we have a plane wave with an energy E. Then the transmission coefficient T, the reflection coefficient R and all elements of a transfer matrix are functions of E. Thus, we are able to study the properties of the system on the base of its scattering response.

Now our task is to find the relation between a transfer matrix formalism and a quantum wave impedance approach. It will enable us to transfer the results obtained for a transfer matrix to the case of a quantum wave impedance.

It follows from the definition of a quantum wave impedance that

$$Z(a) = z_1 \frac{A_+ e^{ik_1 a} - A_- e^{-ik_1 a}}{A_+ e^{ik_1 a} + A_- e^{-ik_1 a}}, \qquad Z(b) = z_2 \frac{B_+ e^{ik_2 a} - B_- e^{-ik_2 a}}{B_+ e^{ik_2 a} + B_- e^{-ik_2 a}},$$

where $z_1 = \sqrt{2(E-U_1)/m} = \frac{\hbar k_1}{m}$ and $z_2 = \sqrt{2(E-U_2)/m} = \frac{\hbar k_2}{m}$ are characteristic impedances of the regions to the left and to the right of the localized potential described by a function $f(x)$ (1), $Z(a)$ and $Z(b)$ is the value of a quantum wave impedance of a studied system at points $x = a$ and $x = b$.

From the other side the definition of a transfer matrix gives

$$\begin{aligned} A_+ e^{ik_1 a} &= T_{11} B_+ e^{ik_2 a} + T_{12} B_- e^{-ik_2 a}, \\ A_- e^{-ik_1 a} &= T_{21} B_+ e^{ik_2 a} + T_{22} B_- e^{-ik_2 a}, \end{aligned} \tag{7}$$

Combining these definitions one gets the following relation:

$$Z(a) = z_1 \frac{(T_{11} - T_{21})(z_2 + Z(b)) + (T_{12} - T_{22})(z_2 - Z(b))}{(T_{11} + T_{21})(z_2 + Z(b)) + (T_{12} + T_{22})(z_2 - Z(b))} \tag{8}$$

or

$$Z(a)=z_1\frac{z_2(T_{11}-T_{21}+T_{12}-T_{22})+Z(b)[T_{11}-T_{21}-T_{12}+T_{22}]}{z_2(T_{11}+T_{21}+T_{12}+T_{22})+Z(b)[T_{11}+T_{21}-T_{12}-T_{22}]}. \tag{9}$$

After introducing Z_{ij} values $(i,j=1,2)$ the last relation can be written as

$$Z(a)=z_1\frac{z_2Z_{11}-Z(b)Z_{12}}{z_2Z_{21}-Z(b)Z_{22}} \tag{10}$$

or in notations of a [26]:

$$Z(a)\to z_1\begin{pmatrix}Z_{11} & Z_{12}\\ Z_{21} & Z_{22}\end{pmatrix}\begin{pmatrix}z_2\\ -Z(b)\end{pmatrix}. \tag{11}$$

The relations between Z_{ij} and T_{ij} are as follows

$$\begin{aligned}
Z_{11} &= \frac{1}{2}\left(T_{11}-T_{21}+T_{12}-T_{22}\right),\\
Z_{12} &= \frac{1}{2}\left(-T_{11}+T_{21}+T_{12}-T_{22}\right),\\
Z_{21} &= \frac{1}{2}\left(T_{11}+T_{21}+T_{12}+T_{22}\right),\\
Z_{22} &= \frac{1}{2}\left(-T_{11}-T_{21}+T_{12}+T_{22}\right).
\end{aligned} \tag{12}$$

A multiplayer $\frac{1}{2}$ is introduced in order to $\det|Z|=\det|T|=1$. We also can express T_{ij} through Z_{ij}, namely

$$\begin{aligned}
T_{11} &= \frac{1}{2}\left(Z_{11}-Z_{12}+Z_{21}-Z_{22}\right),\\
T_{12} &= \frac{1}{2}\left(Z_{11}+Z_{12}+Z_{21}+Z_{22}\right),\\
T_{21} &= \frac{1}{2}\left(-Z_{11}+Z_{12}+Z_{21}-Z_{22}\right),\\
T_{22} &= \frac{1}{2}\left(-Z_{11}-Z_{12}+Z_{21}+Z_{22}\right).
\end{aligned} \tag{13}$$

On the base of the result of [27] if we have a function $f_k(b,a)$ for a considered localized potential described by a function $f(x)$ (1) then we can find both values Z_{ij} and T_{ij}:

$$\begin{aligned}
Z_{11}=\frac{f_k^{(b,a)}(b,a)}{2z_1z_2}, \quad Z_{12}=\frac{f_k^{(a)}(b,a)}{2z_2},\\
Z_{21}=\frac{f_k^{(b)}(b,a)}{2z_1}, \quad Z_{22}=\frac{f_k(b,a)}{2},
\end{aligned} \tag{14}$$

$$
\begin{aligned}
T_{11} &= -\frac{z_1 z_2 f_k(b,a) + z_2 f_k^{(a)}(b,a) - z_1 f_k^{(b)}(b,a) - f_k^{(b,a)}(b,a)}{2 z_1 z_2}, \\
T_{12} &= \frac{z_1 z_2 f_k(b,a) + z_2 f_k^{(a)}(b,a) + z_1 f_k^{(b)}(b,a) + f_k^{(b,a)}(b,a)}{2 z_1 z_2}, \\
T_{21} &= -\frac{z_1 z_2 f_b(b,a) - z_2 f_k^{(a)}(b,a) - z_1 f_k^{(b)}(b,a) + f_k^{(b,a)}(b,a)}{2 z_1 z_2}, \\
T_{22} &= \frac{z_1 z_2 f_k(b,a) - z_2 f_k^{(a)}(b,a) + z_1 f_k^{(b)}(b,a) - f_k^{(b,a)}(b,a)}{2 z_1 z_2}.
\end{aligned}
\tag{15}
$$

For a singular rectangular barrier of U_b height and $L = b - a$ width assuming $E < U_b$ we have

$$
\begin{aligned}
& z_1 = z_2 = z_0 = \sqrt{\frac{2E}{m}}, \quad k_0 = \frac{m}{\hbar} z_0, \quad f_b(b,a) = 2\,\mathrm{sh}[\varkappa_b L], \\
& z_b = \sqrt{\frac{2(E-U_b)}{m}}, \quad \varkappa_b = \frac{\sqrt{2m(U_b - E)}}{\hbar}
\end{aligned}
\tag{16}
$$

and thus

$$
Z = \begin{pmatrix} \frac{\varkappa_b^2}{k_0^2}\,\mathrm{sh}(\varkappa_b L) & i\frac{\varkappa_b}{k_0}\,\mathrm{ch}(\varkappa_b L) \\ -i\frac{\varkappa_b}{k_0}\,\mathrm{ch}(\varkappa_b L) & \mathrm{sh}(\varkappa_b L), \end{pmatrix}, \tag{17}
$$

$$
T = \begin{pmatrix} -i\frac{\varkappa_b^2 - k_0^2}{2k_0\varkappa_b}\mathrm{sh}(\varkappa_b L) + \mathrm{ch}(\varkappa_b L) & -i\frac{k_0^2 + \varkappa_b^2}{2k_0\varkappa_b}\mathrm{sh}(\varkappa_b L) \\ i\frac{k_0^2 + \varkappa_b^2}{2k_0\varkappa_b}\mathrm{sh}(\varkappa_b L) & -i\frac{\varkappa_b^2 - k_0^2}{2k_0\varkappa_b}\mathrm{sh}(\varkappa_b L) + \mathrm{ch}(\varkappa_b L) \end{pmatrix}. \tag{18}
$$

3 Relation between a scattering matrix and a quantum wave impedance

Although the transfer matrix approach is more widely used for an analysis of one-dimensional quantum systems the scattering matrix formalism allows formulating the physical properties of the scattering more easily. Like in a case of a transfer matrix the elements of a scattering matrix completely characterize the scattering and transmission properties of a one-dimensional potential. Scattering matrix describes the outgoing waves in terms of the ingoing waves, namely

$$
\begin{pmatrix} B_+ \\ A_- \end{pmatrix} = S_{ab} \begin{pmatrix} A_+ \\ B_- \end{pmatrix}, \tag{19}
$$

It is well-known that there is a clear correspondence between components of a transfer matrix and a scattering matrix [28]:

$$\begin{aligned} T_{11} &= \frac{1}{S_{11}}, \qquad T_{12} = -\frac{S_{12}}{S_{11}}, \\ T_{21} &= \frac{S_{21}}{S_{11}}, \qquad T_{22} = S_{22} - \frac{S_{12}S_{21}}{S_{11}} \end{aligned} \tag{20}$$

and

$$\begin{aligned} S_{11} &= \frac{1}{T_{11}}, \qquad S_{12} = -\frac{T_{12}}{T_{11}}, \\ S_{21} &= \frac{T_{21}}{T_{11}}, \qquad S_{22} = T_{22} - \frac{T_{12}T_{21}}{T_{11}}. \end{aligned} \tag{21}$$

Using (5) we easily get the components of a scattering matrix expressed through a transmission and a reflection amplitudes:

$$S_{ab} = \begin{pmatrix} t_{ab} & r_{ba} \\ r_{ab} & t_{ba} \end{pmatrix}. \tag{22}$$

On the base of (21) and (15) we have

$$\begin{aligned} S_{11} &= t_{ab} = -\frac{2z_1z_2}{z_1z_2f(b,a) + z_2f_k^{(a)}(b,a) - z_1f_k^{(b)}(b,a) - f_k^{(b,a)}(b,a)}, \\ S_{12} &= r_{ba} = \frac{z_1z_2f_k(b,a) + z_2f_k^{(a)}(b,a) + z_1f_k^{(b)}(b,a) + f_k^{(b,a)}(b,a)}{z_1z_2f_k(b,a) + z_2f_k^{(a)}(b,a) - z_1f_k^{(b)}(b,a) - f_k^{(b,a)}(b,a)}, \\ S_{21} &= r_{ab} = \frac{z_1z_2f_k(b,a) - z_2f_k^{(a)}(b,a) - z_1f_k^{(b)}(b,a) + f_k^{(b,a)}(b,a)}{z_1z_2f_k(b,a) + z_2f_k^{(a)}(b,a) - z_1f_k^{(b)}(b,a) - f_k^{(b,a)}(b,a)}, \\ S_{22} &= t_{ba} = S_{11}. \end{aligned} \tag{23}$$

and

$$\begin{aligned} S_{11} &= S_{22} = \frac{2}{Z_{11} - Z_{12} + Z_{21} - Z_{22}}, \\ S_{12} &= -\frac{Z_{11} + Z_{12} + Z_{21} + Z_{22}}{Z_{11} - Z_{12} + Z_{21} - Z_{22}}, \\ S_{21} &= \frac{-Z_{11} + Z_{12} + Z_{21} - Z_{22}}{Z_{11} - Z_{12} + Z_{21} - Z_{22}}. \end{aligned} \tag{24}$$

4 Quantum wave impedance for a finite cascade of constant potentials

One of the most important properties of a transfer matrix formalism is that the transfer matrix for the whole region of a piecewise constant potential can be calculated as a product of transfer

matrices of each region where a potential has a constant value. So if a potential has the following form

$$U(x) = \begin{cases} 0, & x \leq x_0 \\ U_i(x), & x_i < x < x_{i+1}, i = 1 \dots N \\ 0, & x \geq x_{N+1} \end{cases} \tag{25}$$

and we have a transfer matrix T_i for each region $x \in [x_i \dots x_{i+1}]$. Then the transfer matrix for a whole region is the product of transfer matrices, where each of them corresponds to the appropriate single region:

$$T_{x_0 x_{N+1}} = \prod_{j=0}^{N} T_{x_j x_{j+1}}. \tag{26}$$

It is the consequence of this simple relation: $T_{x_i x_{i+2}} = T_{x_i x_{i+1}} T_{x_{i+1} x_{i+2}}$, which we try to explain below. So the transfer matrix for a single region with a constant potential consists of three multipliers:

$$T_{ab} = I_{12} P_{ab} I_{23}. \tag{27}$$

A first matrix I_{12} and a third one I_{23} describe a wave transferring through the interface of regions with different values of a potential energy. The second matrix P_{ab} describes a wave transferring from a point a to a point b inside one region of a constant potential. Because of very important property of matrices I_{ij} [4]: $I_{ij} = I_{ik} I_{kj}$ we finally get that

$$T_{ac} = I_{12} P_{ab} I_{23} P_{bc} I_{34} = I_{12} P_{ab} I_{21} I_{13} P_{bc} I_{34} = T_{ab} T_{bc}. \tag{28}$$

A special case of the multiplication law (26) is that when in all N regions the function of a potential energy is the same. Then the transfer matrix of the whole system is the transfer matrix of a single region but of power N. Using The Cayley–Hamilton theorem which says that every square matrix satisfies its own characteristic equation [2]:

$$T^2 - 2\chi T + I = 0, \tag{29}$$

where $\chi = \frac{1}{2} Tr(T)$ one can calculate the resulting transfer matrix T in terms of the elements of the transfer matrix of a single region, which finally gives:

$$T^N = T U_{N-1}(\chi) - I U_{N-2}(\chi), \tag{30}$$

where $U_N(\chi)$ is the second kind Chebyshev's polynomial of a degree N in χ. This polynomial obeys the recurrent relation:

$$U_{N+2}(\chi) - 2\chi U_{N+1}(\chi) + U_N(\chi) = 0. \tag{31}$$

Notice that a Chebyshev's second kind polynomial can be shown as:

$$U_N(\chi) = \frac{\sin[(N+1)\lambda(\chi)]}{\sin[\lambda(\chi)]}, \tag{32}$$

where $\lambda = \arccos(\chi)$. Thus, the transfer matrix of a whole system is

$$T^N = \begin{pmatrix} T_{11}U_{N-1}(\chi) - U_{N-2}(\chi) & T_{12}U_{N-1}(\chi) \\ T_{21}U_{N-1}(\chi) & T_{22}U_{N-1}(\chi) - U_{N-2}(\chi) \end{pmatrix}. \tag{33}$$

It gives the expressions for a reflection and a transmission coefficients

$$r = \frac{T_{21}U_{N-1}(\chi)}{T_{11}U_{N-1}(\chi) - U_{N-2}(\chi)}, \quad t = \frac{1}{T_{11}U_{N-1}(\chi) - U_{N-2}(\chi)} \tag{34}$$

and the relation between a quantum wave impedance at the beginning of a studied system and amplitudes A_N and B_N of waves at the end of a system. A_N is the amplitude of a wave which propagates in a positive direction of an axis and B_N is the amplitude of a wave which propagates in a negative direction of an axis.

$$\begin{aligned} Z(0) \;=\; & z_0 \Big([(T_{11} - T_{21})U_{N-1}(\chi) - U_{N-2}(\chi)]A_N - \; [\,(T_{22} - T_{12})U_{N-1}(\chi) - U_{N-2}(\chi)]B_N \Big) \times \\ & \times \; \Big([(T_{11} + T_{21})U_{N-1}(\chi) - U_{N-2}(\chi)]A_N + \; [\,(T_{22} + T_{12})U_{N-1}(\chi) - U_{N-2}(\chi)]B_N \Big)^{-1}. \end{aligned} \tag{35}$$

Taking into account that

$$Z(N) = z_N \frac{A_N - B_N}{A_N + B_N} = z_N \frac{1-\rho}{1+\rho}, \quad \rho = \frac{z_N - Z(N)}{z_N + Z(N)} \tag{36}$$

we finally get

$$\begin{aligned} Z(0) \;=\; & z_0 \Big([T_{11} - T_{21} + T_{12} - T_{22}]U_{N-1}(\chi)z_N + \\ & + \quad (T_{11} - T_{21} + T_{22} - T_{12})U_{N-1}(\chi) - 2U_{N-2}(\chi)]Z(N) \Big) \times \\ & \times \quad \Big([(T_{11} + T_{21} + T_{12} + T_{22})U_{N-1}(\chi) - 2U_{N-2}(\chi)]z_N - \\ & - \quad [T_{22} + T_{12} - T_{11} - T_{21}]U_{N-1}(\chi)Z(N) \Big)^{-1}. \end{aligned} \tag{37}$$

We can rewrite this result using elements of a matrix Z, which we introduced earlier:

$$Z(0) = z_0 \frac{Z_{11}U_{N-1}(\chi)z_N - [Z_{12}U_{N-1}(\chi) + U_{N-2}(\chi)]Z(N)}{[Z_{21}U_{N-1}(\chi) - U_{N-2}(\chi)]z_N - \; Z_{22}U_{N-1}(\chi)Z(N)} \tag{38}$$

keeping in mind that the values Z_{ij} are defined on the base of a relation (12). Thus, the problem of a calculation of a quantum wave impedance for a system of identical regions of a potential is solved. And once the expression for a quantum wave impedance for a single region is obtained it can be easily extended to the analytical calculation of a quantum wave impedance for N identical potentials, like it is for a transfer matrix approach.

5 Finite periodic systems

The aim of this section is to present an introduction of an application of a quantum wave impedance to finite periodic systems.

So let's consider the model with the following potential energy:

$$U(x) \quad = \quad U_1\theta(-x-l_L-l)+U_0(x)(\theta(x)-\theta(x-L))+U_2\theta(x-L-l_R), \tag{39}$$

where $U(x)$ is a periodic function with a period a, $l_L, l_R \geq 0$, $L = Nl$, N is the number of elementary cells.

In a previous section we have found the relation (38) which in our case can be written as:

$$Z(0) = z_0\frac{Z_{11}U_{N-1}(\chi)z_N - [Z_{12}U_{N-1}(\chi)+U_{N-2}(\chi)]Z(L)}{[Z_{21}U_{N-1}(\chi)-U_{N-2}(\chi)]z_N - Z_{22}U_{N-1}(\chi)Z(L)}, \tag{40}$$

where $Z_{ij}, i, j = 1..2$ are determined on the base of the expression which relates the value of a quantum wave impedance at the boundary points of the elementary cell (10).

Notice that these relations are independent of a specific potential profile, so it can be used to obtain a quantum wave impedance of a periodic system with an arbitrary potential profile including a piecewise constant periodic potential. Having a quantum wave impedance of a periodic system, we are able to get expressions for a transmission and a reflection coefficients.

Then using iterative formulas for a quantum wavimpedance determination we find that

$$\begin{aligned} Z(-l_L-l) \quad &= \quad z_0\frac{Z(0)\,\mathrm{ch}[\gamma_0(l_L+l)]-z_0\,\mathrm{sh}[\gamma_0(l_L+l)]}{z_0\,\mathrm{ch}[\gamma_0(l_L+l)]-Z(0)\,\mathrm{sh}[\gamma_0(l_L+l)]}, \\ Z(L) \quad &= \quad z_N\frac{z_R\,\mathrm{ch}[\gamma_N l_R]-z_N\,\mathrm{sh}[\gamma_N l_R]}{z_N\,\mathrm{ch}[\gamma_N l_R]-z_R\,\mathrm{sh}[\gamma_N l_R]}, \end{aligned} \tag{41}$$

where $\gamma_0 = imz_0/\hbar$, $\gamma_N = imz_N/\hbar$. Expressing $Z(0)$ and $Z(L)$ from these relations, substituting them into (40) and reminding the condition for eigenenergies determination ($Z(-l_1-l) = -z_L$) we get the following formula:

$$\begin{aligned} &\frac{z_0\,\mathrm{th}[\gamma_0(l_L+l)]-z_L}{z_0-z_L\,\mathrm{th}[\gamma_0(l_L+l)]} = \Big(Z_{11}U_{N-1}(\chi)(z_N-z_R\,\mathrm{th}[\gamma_N l_R]) \\ &-[Z_{12}U_{N-1}(\chi)+U_{N-2}(\chi)]\ \ (z_R-z_N\,\mathrm{th}[\gamma_N l_R])\Big) \\ &\Big([Z_{21}U_{N-1}(\chi)-U_{N-2}(\chi)](z_N-z_R\,\mathrm{th}[\gamma_N l_R])- \\ &-Z_{22}U_{N-1}(\chi)(z_R-z_N\,\mathrm{th}[\gamma_N l_R])\Big)^{-1}. \end{aligned} \tag{42}$$

6 Finite Dirac comb

In this section we discuss a system, properties of which is periodic along the length of the system. So, consider a finite Dirac comb with a following form of a potential energy:

$$U(x) = U_L\theta(-x-l) + \sum_{n=0}^{N-1} \alpha\delta(x+nl)(\theta(x)-\theta(x-L)) + U_R\theta(x-L). \tag{43}$$

For the first time this model was solved by Sokolov in 1934 [29]. He based on the Tamm's approach but extended it and proposed an original way of studying surface states. In this section we will show how to solve this model using a quantum wave impedance approach.

So, for a single cell of a Dirac comb we have

$$\begin{aligned} Z(a) = z_0\frac{Z(b)\,\mathrm{ch}[ik_0l] - z_0\,\mathrm{sh}[ik_0l]}{z_0\,\mathrm{ch}[ik_0l] - Z(b)\,\mathrm{sh}[ik_0l]} + i\frac{2\alpha}{\hbar} = \\ + z_0\frac{z_0(-\,\mathrm{sh}[-i\xi] + 2i\Omega\,\mathrm{ch}[i\xi]) - Z(b)(-\,\mathrm{ch}[i\xi] + 2i\Omega\,\mathrm{sh}[i\xi])}{z_0\,\mathrm{ch}[i\xi] - Z(b)\,\mathrm{sh}[i\xi]}, \end{aligned} \tag{44}$$

where $\Omega = p/\xi = \alpha/(z_0\hbar)$, $z_0 = \sqrt{2mE/2}$, $\xi = k_0l$, $k_0 = mz_0/\hbar$, $p = m\alpha l/\hbar^2$.

On the base of a formula (10) we have

$$\begin{aligned} Z_{11} = -\,\mathrm{sh}[i\xi] + 2i\Omega\,\mathrm{ch}[i\xi], \qquad & Z_{12} = -\,\mathrm{ch}[i\xi] + 2i\Omega\,\mathrm{sh}[i\xi], \\ Z_{21} = \mathrm{ch}[i\xi], \qquad & Z_{22} = \mathrm{sh}[i\xi]. \end{aligned} \tag{45}$$

But before proceeding we have to be convinced that $\det|Z| = 1$. We can see this by substituting expressions for Z_{ij} (45) into the formula for $\det|Z| = Z_{11}Z_{22} - Z_{12}Z_{21}$.

In a case of a considered here system we have that $l_L = a$, $l_R = 0$, $z_N = z_0$. For a simplification of a process of a calculation let's assume that $z_L = z_R = z = z_E$ ($z_E = \sqrt{2(E-U_E)/m}$). Applying both these and the values for Z_{ij} to the obtained in the previous section formula (42) we get the relation for the determination of eigenenergies, namely

$$\frac{z_0\,\mathrm{th}[i\xi] - z_E}{z_0 - z_E\,\mathrm{th}[i\xi]} = \frac{Z_{11}U_{N-1}(\chi)z_0 - [Z_{12}U_{N-1}(\chi) + U_{N-2}(\chi)]z_E}{[Z_{21}U_{N-1}(\chi) - U_{N-2}(\chi)]z_0 - Z_{22}U_{N-1}(\chi)z_E}. \tag{46}$$

After expressing $U_{N-2}(\chi)/U_{N-1}(\chi)$ we can rewrite the previous relation in the following form:

$$\frac{(Z_{21}z_0 - Z_{22}z_E)(z_0\,\mathrm{th}[i\xi] - z_E) - (Z_{11}z_0 + Z_{12}z_E)(z_0 - z_E\,\mathrm{th}[i\xi])}{(z_0^2 + z_E^2)\,\mathrm{th}[i\xi] - 2z_0z_E} = \frac{U_{N-2}(\chi)}{U_{N-1}(\chi)}. \tag{47}$$

Taking into account that

$$U_N(\chi) - 2\cos(\chi)U_{N-1}(\chi) + U_{N-2}(\chi) = 0 \tag{48}$$

we find

$$\frac{U_{N-2}(\chi)}{U_{N-1}(\chi)} = 2\cos(\chi) - \frac{U_N(\chi)}{U_{N-1}(\chi)} = 2\cos(\chi) - \frac{\sin((N+1)\chi)}{(\sin(N\chi))} = \\ = 2\cos(\chi) - \frac{1}{\cos(\chi) - \sin(\chi)\,\mathrm{ctg}((N+1)\chi)}. \tag{49}$$

And finally we get the following expression for the determination of energies of surface states:

$$\cos(\chi) - \sin(\chi)\,\mathrm{ctg}((N+1)\chi) = \Big[\, 2\cos(\chi) - \\ - \frac{(Z_{21}z_0 - Z_{22}z_E)(z_0\mathrm{tg}[i\xi] - z_E) - (Z_{11}z_0 + Z_{12}z_E)(z_0 - z_E\mathrm{tg}[i\xi])}{(z_0^2 + z_E^2)\,\mathrm{tg}[i\xi] - 2z_0z_E} \Big]^{-1}, \tag{50}$$

where

$$\cos(\chi) = \cos(\xi) + \Omega\sin(\xi). \tag{51}$$

Taking into account the expressions for Z_{ij} (45) and that $\cos(\chi) = (Z_{21} - Z_{12})/2$ we get

$$\cos(\chi) - \sin(\chi)\,\mathrm{ctg}((N+1)\chi) = \frac{i(z_0^2 + z_E^2)\sin[\xi] - 2z_0z_E\cos[\xi]}{2i\Omega z_0^2 - 2z_0z_E} = \\ = \frac{(-\varkappa_E^2/k_0^2 + 1)\sin[\xi] - 2\varkappa_E/k_0\cos[\xi]}{2(\Omega - k_0/\varkappa_E)}. \tag{52}$$

7 Finite Dirac comb. Transfer matrix approach

Using relation (13) and expressions for reflection amplitudes r_0 and r_N [20] at the beginning ($x = -l$) and at the end ($x = L$) of a studied system

$$r_0 = \exp[-2i\xi]\frac{z_0 + z_E}{z_0 - z_E}, \quad r_N = \frac{z_0 - z_E}{z_0 + z_E} \tag{53}$$

we can rewrite a formula (50) in the following form:

$$\cos(\chi) - \sin(\chi)\,\mathrm{ctg}((N+1)\chi) = \\ = \frac{r_N - r_0}{r_0T_{11} + r_0r_NT_{12} - T_{21} - T_{22}r_N - 2\cos(\chi)(r_0 - r_N)}. \tag{54}$$

Now taking into account that $2\cos(\chi) = T_{11} + T_{22}$ we get

$$\cos(\chi) - \sin(\chi)\,\mathrm{ctg}((N+1)\chi) = \frac{r_N - r_0}{r_NT_{11} + r_0r_NT_{12} - T_{21} - T_{22}r_0}. \tag{55}$$

Using the relation (13) we can calculate the transfer matrix for a single cell of a Dirac comb:

$$T = \begin{pmatrix} (1 + i\Omega)\exp(-i\xi), & i\Omega\exp(i\xi) \\ -i\Omega\exp(-i\xi), & (1 - i\Omega)\exp(i\xi) \end{pmatrix}. \tag{56}$$

Substituting the elements of the obtained transfer matrix into the relation (55) and after simple transformations we get

$$\sin(\chi)\,\mathrm{ctg}((N+1)\chi) - \cos(\chi) = \frac{(\varkappa_E^2/k_0^2 - 1)\sin(\xi) + 2\varkappa_E/k_0\cos(\xi)}{2(\beta - \varkappa_E/k_0)}. \tag{57}$$

We also can depict this result in a form used in the paper [30]

$$\mathrm{ctg}[(N+1)\chi] = \frac{\mu^2 - 1}{\mu}, \tag{58}$$

where

$$\mu = \frac{\sin(\chi)}{(\varkappa_E/k_0 - \beta)\sin(\xi)}, \tag{59}$$

and $\varkappa_E = \sqrt{2(U_E - E)/m}$.

8 Conclusions

The models of finite periodic systems play very important role in a study of nanoheterostructures. They give us the possibility to investigate surface states and impurity states analytically. Another widely-investigated problem which is closely related to this topic is the properties of classical waves in such periodically layered structures as phononic and photonic crystals. The character feature of these systems is that the periodic structure can be flexibly designed and shaped, and this fact among other things gives the opportunity to tailor the boundary-dependent states by a specific choice of a surface location.

So, effective methods for a study of finite systems are of great interest. It is obvious that when we move from the one barrier/well system to the double barrier/well system the complexity of a calculation of a quantum wave impedance increases. And naturally one expects the enormous growing a complexity for a big number of barriers/wells. But in this paper we showed that it is not a case for periodic systems not only within a transfer matrix approach but also within a quantum wave impedance method. We demonstarated how to get compact expressions for a quantum wave impedance of a finite periodic system by using properties and symmetries of a transfer matrix.

Following the aim of finding effective methods of finit periodic systems investigation we derived the relation between a transfer matrix formalize and a quantum wave impedance approach in order to combine the advantages of both methods. The application of obtained results we illustrated on a finite Dirac comb and within developed approach we get the expressions for a Tamm's levels in this system.

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